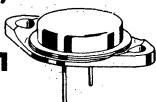


# 2N376A (GERMANIUM)

For Specifications, See 2N350A Data.

## 2N378 thru 2N380 (GERMANIUM)

### 2N459, A



CASE 11  
(TO-3)

PNP germanium power transistors for general purpose power amplifier and switching applications.

#### MAXIMUM RATINGS

Rating	Symbol	2N378	2N379	2N380	2N459	2N459A	Unit
Collector-Emitter Voltage	$V_{CEO}$	20	40	30	60	60	Vdc
Collector-Emitter Voltage ( $V_{BE} = 1.5$ V) ( $V_{BE} = 1.0$ V)	$V_{CEX}$	40	80	60	-	-	Vdc
Collector-Emitter Voltage	$V_{CES}$	-	-	-	70	70	Vdc
Collector-Base Voltage	$V_{CB}$	-	-	-	-	105	Vdc
Emitter-Base Voltage	$V_{EB}$	-	-	-	10	25	Vdc
Collector Current	$I_C$	5.0				mA	
Operating Junction Temperature Range	$T_J$	-65 to +110				°C	
Total Device Dissipation @ $T_C = 25$ °C	$P_D$	106				Watts	

#### ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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#### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C = 100$ mA)	$2N378$ $2N379$ $2N380$ $2N459, 2N459A$	$BV_{CEO}$	20 40 30 60	-	Vdc
Collector Cutoff Current ( $V_{CE} = 40$ Vdc, $V_{BE(off)} = 1.5$ Vdc) ( $V_{CE} = 60$ Vdc, $V_{BE(off)} = 1.5$ Vdc) ( $V_{CE} = 80$ Vdc, $V_{BE(off)} = 1.5$ Vdc) ( $V_{CE} = 105$ Vdc, $V_{BE(off)} = 1.5$ Vdc) ( $V_{CE} = 105$ Vdc, $V_{BE(off)} = 1.0$ Vdc)	$2N378$ $2N380$ $2N379$ $2N459$ $2N459A$	$I_{CEX}$	- - - - -	10 10 10 10 10	mA
Collector Cutoff Current ( $V_{CB} = 25$ Vdc) ( $V_{CB} = 25$ Vdc, $T_C = 85$ °C)		$I_{CBO}$	- -	0.5 7.5	mA
Emitter Cutoff Current ( $V_{BE} = 10$ Vdc) ( $V_{BE} = 25$ Vdc)	$2N380$ $2N459$ $2N459A$	$I_{EBO}$	- - -	1.5 2.0 2.0	mA

**2N378, thru 2N380 2N459, 2N459 A (continued)****ELECTRICAL CHARACTERISTICS (continued)**

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = 2.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ )  ( $I_C = 5.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ )	$h_{FE}$	40 20 30 40 20	80 70 70 70 -	-
Collector-Emitter Saturation Voltage ( $I_C = 2.0 \text{ Adc}$ , $I_B = 0.2 \text{ Adc}$ )	$V_{CE(\text{sat})}$	- -	1.0 0.3	Vdc
Base-Emitter Voltage ( $I_C = 2.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ )	$V_{BE(on)}$	- - -	1.6 1.3 1.0	Vdc
<b>DYNAMIC CHARACTERISTICS</b>				
Common-Emitter Cutoff Frequency ( $I_C = 1.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ ) ( $I_C = 2.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ )	$f_{\alpha e}$	5.0 5.0	- -	kHz